APR 1 3 2005 W

TITLE: FLASH MEMORY CELL HAVING REDUCED LEAKAGE CURRENT INVENTOR(S): Sheung Hee Park, Richard M. Fastow, and Dong-Hyuk Ju USSN: 10/618,191 Attorney Docket #: AMD-H0534

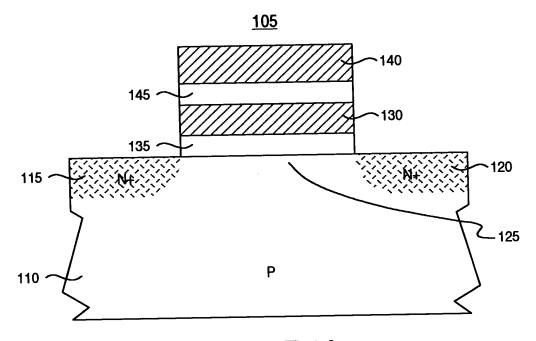


FIGURE 1A (CONVENTIONAL ART)

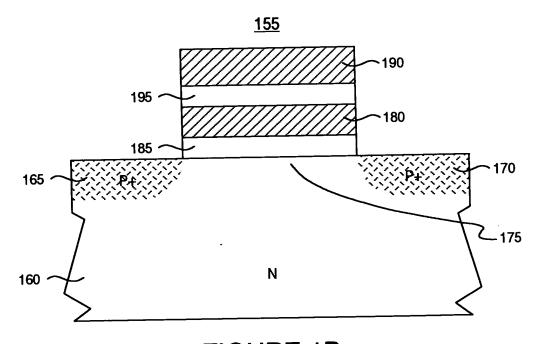


FIGURE 1B (CONVENTIONAL ART)

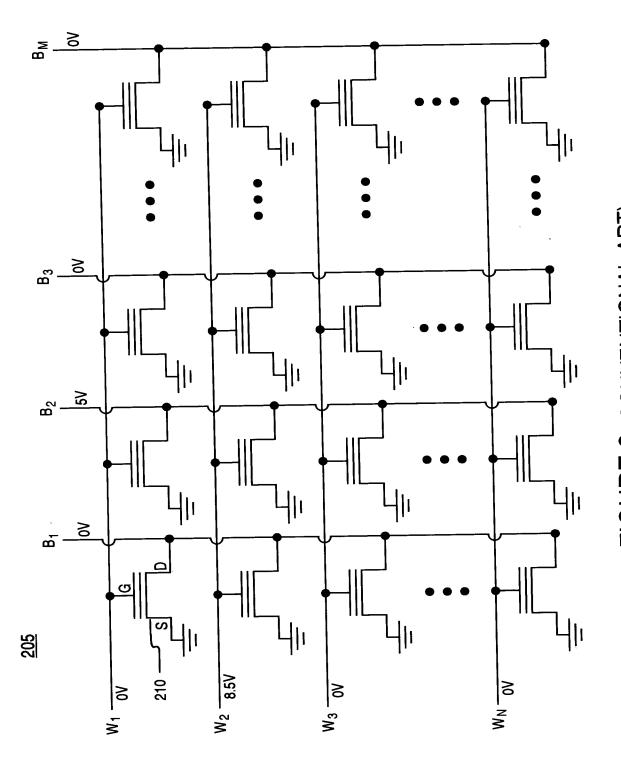


FIGURE 2 (CONVENTIONAL ART)

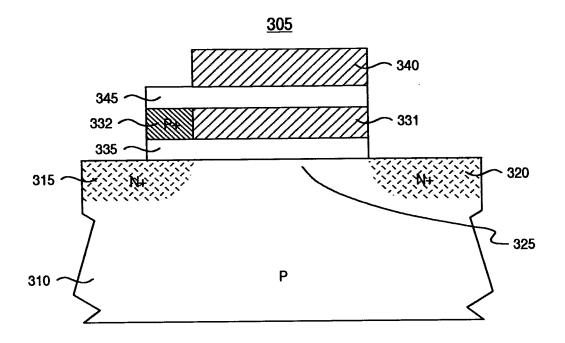


FIGURE 3

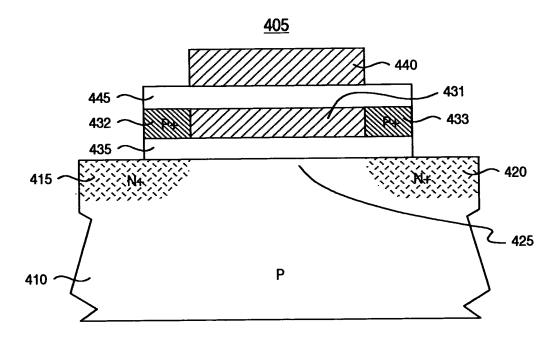


FIGURE 4

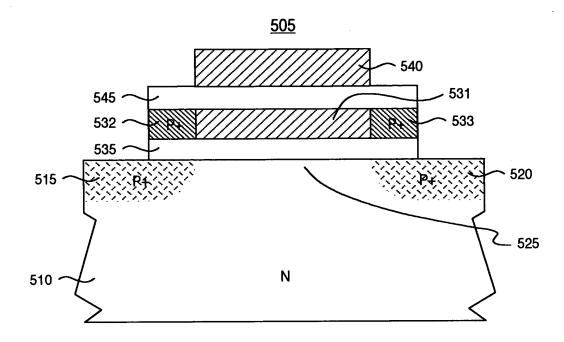


FIGURE 5

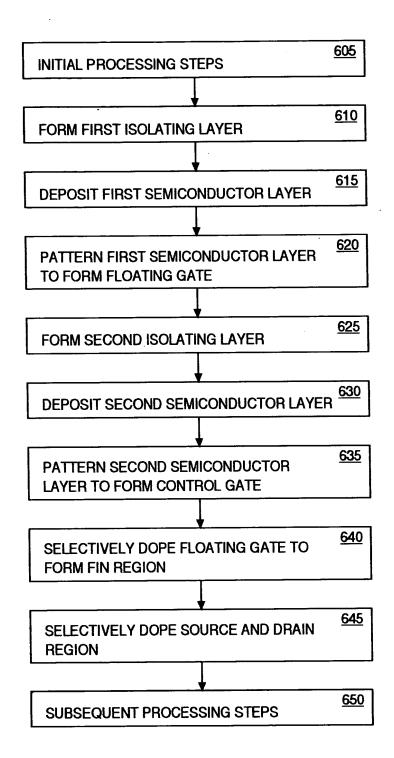


FIGURE 6